

S1W0-xxxxxx03-0000000-x0001 - High-power LED

New Generation of WICOP

High-Power LED – WICOP-22 & 22P S1W0-xxxxxx03-0000000-x0001 (Cool, Neutral, Warm)







Product Brief

Description

- The WICOP series is designed for high flux output applications with high current operation capability.
- Compact footprint(2.21x2.21mm) enables system level cost saving
- It incorporates state of the art SMD design and low thermal resistant material.
- •
- The WICOP is ideal light sources for directional lighting applications such as Spot Lights, various outdoor applications, automotive lightings and high performance torches.

Features and Benefits

- Designed for high current operation
- Low Thermal Resistance
- A wide CCT range of 2,600~7,000K
- ANSI compliant Binning
- RoHS compliant
- Phosphor film directly attached to chip surface

Key Applications

- Residential Replacement lamps
- Commercial/Industrial Retail Display
- Outdoor area Flood/Street light, High Bay

CRI Nominal **Reference Code** Color Part Number ССТ Min S1W0-2222657003-00000000-00001 6500K (S1W0-2222657003-00000000-P0001) SZ8-Y22-W0-C7 Cool S1W0-2222577003-00000000-00001 5700K (SZ8-Y22-W0-C7-P) White (S1W0-2222577003-00000000-P0001) S1W0-2222507003-00000000-00001 5000K (S1W0-2222507003-00000000-P0001) Neutral SZ8-Y22-WN-C7 S1W0-2222407003-00000000-00001 4000K 70 (SZ8-Y22-WN-C7-P) White (S1W0-2222407003-00000000-P0001) S1W0-2222357003-00000000-00001 3500K (S1W0-2222357003-00000000-P0001) S1W0-2222307003-00000000-00001 SZ8-Y22-WW-C7 Warm 3000K (SZ8-Y22-WW-C7-P) (S1W0-2222307003-00000000-P0001) White S1W0-2222277003-00000000-00001 2700K (S1W0-2222277003-00000000-P0001)

Table 1. Product Selection Table



Table 1-2. Product Selection Table

SEOUL

| Deference Code | Color | Nominal | Dort Number | CRI |
|------------------------------------|------------------|---------|--|--|
| Reference Code | Color | ССТ | Part Number | Min |
| | | 6500K | S1W0-2222658003-00000000-00001 (S1W0-2222658003-00000000-P0001) | |
| SZ8-Y22-W0-C8 (SZ8-Y22-W0-C8-P) | Cool White | 5700K | S1W0-2222578003-00000000-00001 (S1W0-2222578003-00000000-P0001) | |
| | | 5000K | S1W0-2222508003-00000000-00001 (S1W0-2222508003-00000000-P0001) | |
| SZ8-Y22-WN-C8 (SZ8-Y22-WN-C8-P) | Neutral White | 4000K | S1W0-2222408003-00000000-00001 (S1W0-2222408003-00000000-P0001) | 80 |
| | | 3500K | S1W0-2222358003-00000000-00001 (S1W0-2222358003-00000000-P0001) | |
| | Warm White | | 3000K | S1W0-2222308003-00000000-00001 (S1W0-2222308003-00000000-P0001) |
| | | 2700K | S1W0-2222278003-00000000-00001 (S1W0-2222278003-00000000-P0001) | |
| | | 6500K | S1W0-2222659003-00000000-00001 (S1W0-2222659003-00000000-P0001) | |
| SZ8-Y22-W0-C9 (SZ8-Y22-W0-C9-P) | Cool White | 5700K | S1W0-2222579003-00000000-00001 (S1W0-2222579003-00000000-P0001) | |
| | | 5000K | S1W0-2222509003-00000000-00001 (S1W0-2222509003-00000000-P0001) | |
| SZ8-Y22-WN-C9 (SZ8-Y22-WN-C9-P) | Neutral White | 4000K | S1W0-2222409003-00000000-00001 (S1W0-2222409003-00000000-P0001) | 90 |
| | | 3500K | S1W0-2222359003-00000000-00001 (S1W0-2222359003-00000000-P0001) | |
| SZ8-Y22-WW-C9 (SZ8-Y22-WW-C9-P) | Warm White | 3000K | S1W0-2222309003-00000000-00001 (S1W0-2222309003-00000000-P0001) | |
| | | 2700K | S1W0-2222279003-00000000-00001 (S1W0-2222279003-00000000-P0001) | |





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S1W0-xxxxxx03-0000000-x0001 - High-power LED

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Performance Characteristics

SEOUL

Typ. Luminous Тур. Flux Φ_v^[3] [lm] Luminous Min. Min. Nominal Efficacy CCT [K] CRI, Flux Part Number [Im/W] $R_{a^{[4]}}$ [lm] 1000mA 1500mA 700mA @700mA S1W0-2222657003-00000000-00001 S1W0-2222577003-00000000-00001 S1W0-2222507003-00000000-00001 S1W0-2222407003-00000000-00001 S1W0-2222357003-00000000-00001 S1W0-2222307003-00000000-00001 S1W0-2222277003-0000000-00001 S1W0-2222658003-0000000-00001 S1W0-2222578003-0000000-00001 S1W0-2222508003-0000000-00001 S1W0-2222408003-0000000-00001 S1W0-2222358003-0000000-00001 S1W0-2222308003-0000000-00001 S1W0-2222278003-0000000-00001 S1W0-2222659003-0000000-00001 S1W0-2222579003-0000000-00001 S1W0-2222509003-0000000-00001 S1W0-2222409003-00000000-00001 S1W0-2222359003-00000000-00001 S1W0-2222309003-0000000-00001 S1W0-2222279003-0000000-00001

Table 2. Electro Optical Characteristics, I_F = 700mA, T_i=85°C

Note :

- (1) Correlated Color Temperature is derived from the CIE 1931 Chromaticity diagram.
 - Color coordinate : ±0.005, CCT ±5% tolerance.
- (2) Seoul Semiconductor maintains a tolerance of $\pm 7\%$ on flux and power measurements.
- (3) Φ_V is the total luminous flux output as measured with an integrating sphere.
- (4) Tolerance is ± 2.0 on CRI measurements.



Performance Characteristics

SEOUL

Typ. Luminous Тур. Flux Φ_v^[3] [lm] Luminous Min. Min. Nominal Efficacy CCT [K] CRI, Flux Part Number [Im/W] $R_{a^{[4]}}$ [lm] 1000mA 1500mA 700mA @700mA S1W0-2222657003-00000000-P0001 S1W0-2222577003-00000000-P0001 S1W0-2222507003-00000000-P0001 S1W0-2222407003-00000000-P0001 S1W0-2222357003-00000000-P0001 S1W0-2222307003-00000000-P0001 S1W0-2222277003-00000000-P0001 S1W0-2222658003-00000000-P0001 S1W0-2222578003-00000000-P0001 S1W0-2222508003-00000000-P0001 S1W0-2222408003-00000000-P0001 S1W0-2222358003-00000000-P0001 S1W0-2222308003-00000000-P0001 S1W0-2222278003-00000000-P0001 S1W0-2222659003-00000000-P0001 S1W0-2222579003-00000000-P0001 S1W0-2222509003-00000000-P0001 S1W0-2222409003-00000000-P0001 S1W0-2222359003-00000000-P0001 S1W0-2222309003-00000000-P0001 S1W0-2222279003-00000000-P0001

Table 2. Electro Optical Characteristics, I_F = 700mA, T_i=85°C

Note :

(1) Correlated Color Temperature is derived from the CIE 1931 Chromaticity diagram.

Color coordinate : ± 0.005 , CCT $\pm 5\%$ tolerance.

- (2) Seoul Semiconductor maintains a tolerance of $\pm 7\%$ on flux and power measurements.
- (3) $\Phi_{\rm V}$ is the total luminous flux output as measured with an integrating sphere.
- (4) Tolerance is ± 2.0 on CRI measurements.



Performance Characteristics

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Table 3. Absolute Maximum Ratings

| Parameter | Symbol | | | Unit | |
|---------------------------------|-----------------|---------|--------------------|---------|--------|
| Farameter | Symbol | Min. | Тур. | Max. | Unit |
| Forward Current [1] | I _F | - | 0.7 | 2.0 [3] | А |
| Power Dissipation | P _D | - | - | 6.5 | W |
| Junction Temperature | T_{j} | - | - | 145 | °C |
| Storage Temperature | T_{stg} | - 40 | - | 125 | °C |
| Viewing angle | θ | | 140 | | degree |
| Forward voltage (700mA, 85°C) | V _F | | 2.78 | 3.00 | V |
| Thermal resistance (J to S) [2] | $R\theta_{J-S}$ | - | 4.0 ^[3] | - | K/W |
| ESD Sensitivity(HBM) | | Class 2 | JEDEC JS-0 | 01-2017 | |

Note :

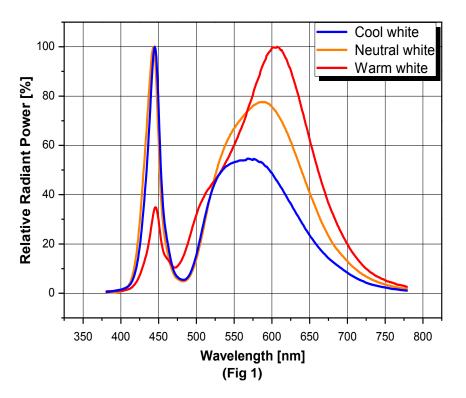
(1) At Junction Temperature 85° C condition.

- (2) $R\theta_{J-S}$ is tested at 700mA.
- (3) Using Metal PCB (Normal type).
- Thermal resistance can be increased substantially depending on the heat sink design/operating condition, and the maximum possible driving current will decrease accordingly.

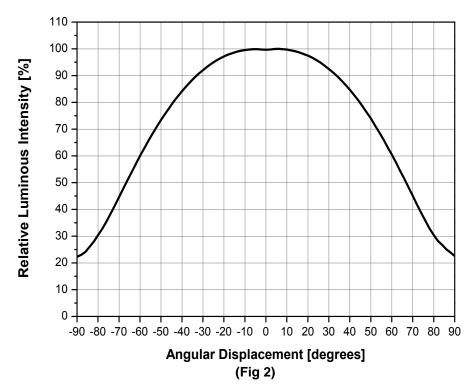
Characteristics Graph

Color Spectrum

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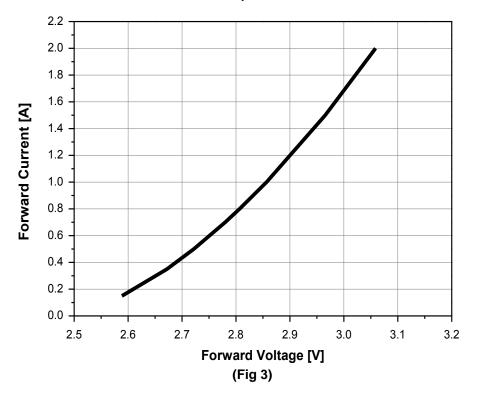
Typical Spatial Distribution



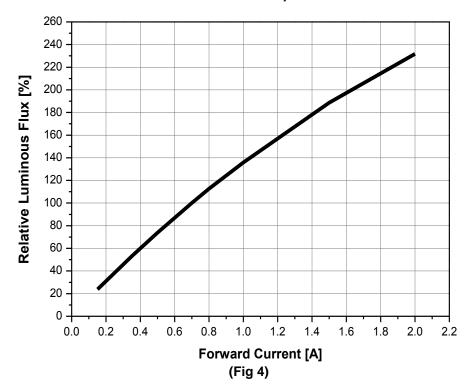
Characteristics Graph

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Forward Voltage vs. Forward Current, T_j=85°C



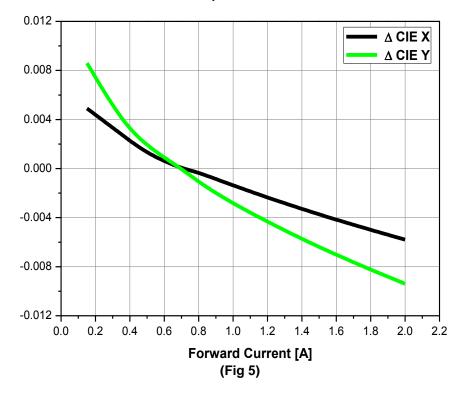
Forward Current vs. Relative Luminous Flux, T_i=85°C



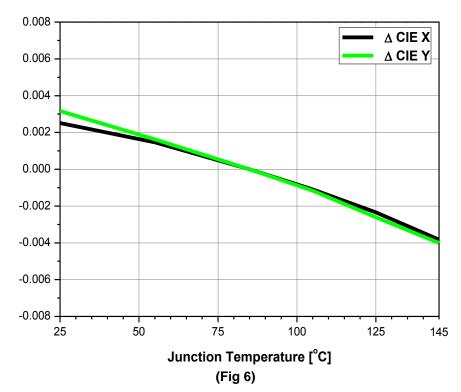
Characteristics Graph

SEOUL

Forward Current. vs. CIE X, Y Shift, Tj=85°C



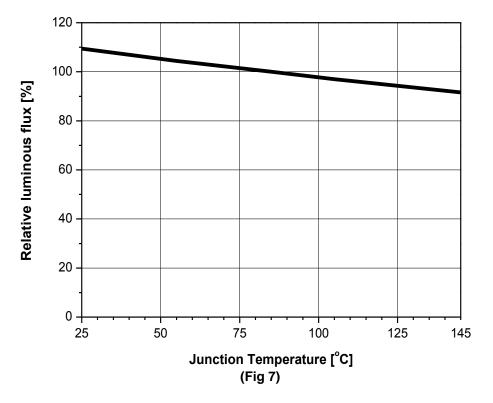
Junction Temp. vs. CIE X, Y Shift, I_F=700mA



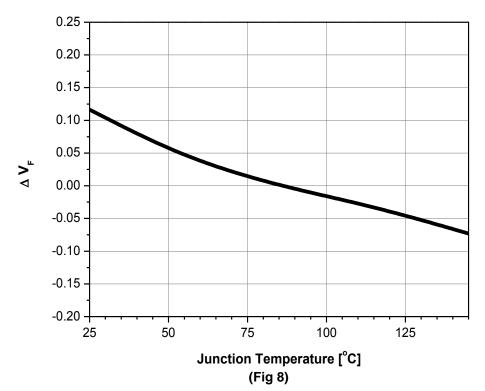


Characteristics Graph

Junction Temp. vs. Relative Luminous Flux, I_F=700mA



Junction Temp. vs. Relative Forward Voltage, I_F=700mA

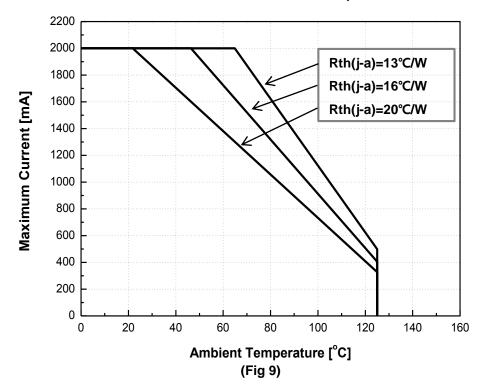




Characteristics Graph

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Color Bin Structure

Table 4. Bin Code description, I_F=700mA, T_i=85°C

<CRI 70>

SEOUL

| Part Number | Luminous Flux [lm] | | | Color Chromaticity | Typical Forward Voltage $[V_F]^{[1]}$ | | |
|-------------------------------|--------------------|------|------|-----------------------|---------------------------------------|------|------|
| | Bin Code | Min. | Max. | Coordinate | Bin Code | Min. | Max. |
| | W2 | 254 | 271 | Refer to page. | | 2.50 | |
| S1W0- 2222xx7003- | W3 | 271 | 285 | | F | | 2.75 |
| 0000000-00001 | W4 | 285 | 299 | | | | |
| S1W0- | W5 | 299 | 313 | 14~16 | G | 2.75 | |
| 2222xx7003- 00000000-P0001 | W6 | 313 | 327 | - | | | 3.00 |
| | W7 | 327 | 341 | | | | |

<CRI 80>

| Part Number | Luminous Flux [lm] | | | Color Chromaticity | Typical Forward Voltage $[V_F]^{[1]}$ | | |
|-------------------------------|--------------------|------|------|-----------------------|---------------------------------------|------|------|
| | Bin Code | Min. | Max. | Coordinate | Bin Code | Min. | Max. |
| | W2 | 254 | 271 | Refer to page. | | 2.50 | |
| S1W0- 2222xx8003- | W3 | 271 | 285 | | F | | 2.75 |
| 0000000-00001 | W4 | 285 | 299 | | | | |
| S1W0- | W5 | 299 | 313 | 14~16 | G | 2.75 | 3.00 |
| 2222xx8003- 00000000-P0001 | W6 | 313 | 327 | - | | | |
| | W7 | 327 | 341 | | | | |

<CRI 90>

| Part Number | Luminous Flux [lm] | | | Color Chromaticity | Typical Forward Voltage [V _F] ^{[1] *} | | |
|-------------------------------|--------------------|------|------|-----------------------|--|------|------|
| | Bin Code | Min. | Max. | Coordinate | Bin Code | Min. | Max. |
| | V1 | 195 | 208 | Refer to page. | | 2.50 | |
| S1W0- 2222xx9003- | V2 | 208 | 223 | | F G | | 2.75 |
| 00000000-00001 | V3 | 223 | 237 | | | | |
| S1W0- | W1 | 237 | 254 | 14~16 | | | |
| 2222xx9003- 00000000-P0001 | W2 | 254 | 271 | - | | | |
| | W3 | 271 | 285 | | | | |

Notes :

(1) Tolerance is $\pm 0.06V$ on forward voltage measurements.

Available Rank

S1W0-xxxxxxx03-00000000-x0001 - High-power LED

Color Bin Structure

Table 5. Luminous Flux rank distribution (CRI70)

<CRI70>

SEOUL

| сст | CIE | Luminous Flux Rank | | | | | |
|----------------|-----|--------------------|----|----|----|----|----|
| 6,000 ~ 7,000K | А | W2 | W3 | W4 | W5 | W6 | W7 |
| 5,300 – 6,000K | В | W2 | W3 | W4 | W5 | W6 | W7 |
| 4,700 ~ 5,300K | С | W2 | W3 | W4 | W5 | W6 | W7 |
| 3,700 ~ 4,200K | Е | W2 | W3 | W4 | W5 | W6 | W7 |
| 3,200 ~ 3,700K | F | W2 | W3 | W4 | W5 | W6 | W7 |
| 2,900 ~ 3,200K | G | W2 | W3 | W4 | W5 | W6 | W7 |
| 2,600 ~ 2,900K | н | W2 | W3 | W4 | W5 | W6 | W7 |

<CRI80>

| сст | CIE | Luminous Flux Rank | | | | | |
|----------------|-----|--------------------|----|----|----|----|----|
| 6,000 ~ 7,000K | А | W2 | W3 | W4 | W5 | W6 | W7 |
| 5,300 – 6,000K | В | W2 | W3 | W4 | W5 | W6 | W7 |
| 4,700 ~ 5,300K | С | W2 | W3 | W4 | W5 | W6 | W7 |
| 3,700 ~ 4,200K | Е | W2 | W3 | W4 | W5 | W6 | W7 |
| 3,200 ~ 3,700K | F | W2 | W3 | W4 | W5 | W6 | W7 |
| 2,900 ~ 3,200K | G | W2 | W3 | W4 | W5 | W6 | W7 |
| 2,600 ~ 2,900K | н | W2 | W3 | W4 | W5 | W6 | W7 |

<CRI90>

| сст | CIE | Luminous Flux Rank | | | | | |
|----------------|-----|--------------------|----|----|----|----|----|
| 6,000 ~ 7,000K | А | V1 | V2 | V3 | W1 | W2 | W3 |
| 5,300 – 6,000K | В | V1 | V2 | V3 | W1 | W2 | W3 |
| 4,700 ~ 5,300K | С | V1 | V2 | V3 | W1 | W2 | W3 |
| 3,700 ~ 4,200K | Е | V1 | V2 | V3 | W1 | W2 | W3 |
| 3,200 ~ 3,700K | F | V1 | V2 | V3 | W1 | W2 | W3 |
| 2,900 ~ 3,200K | G | V1 | V2 | V3 | W1 | W2 | W3 |
| 2,600 ~ 2,900K | н | V1 | V2 | V3 | W1 | W2 | W3 |

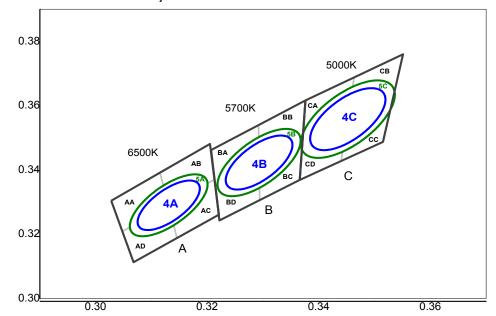
Notes :

(1) Tolerance is $\pm 0.06V$ on forward voltage measurements.

Color Bin Structure

SEOUL

CIE Chromaticity Diagram, T_j=85°C, I_F=700mA



| 6500 | K 4Step | 5700 | K 4Step | 5000K 4Step | | |
|---------------------------|-----------------|---------------------------|-----------------|---------------------------|-----------------|--|
| | 4A |] | 4B | 4C | | |
| Center point | 0.3123 : 0.3282 | Center point | 0.3287 : 0.3417 | Center point | 0.3447 : 0.3553 | |
| Major Axis a | 0.0088 | Major Axis a | 0.0095 | Major Axis a | 0.0108 | |
| Minor Axis b | 0.0036 | Minor Axis b | 0.0040 | Minor Axis b | 0.0047 | |
| Ellipse Rotation Angle | 58 | Ellipse Rotation Angle | 59 | Ellipse Rotation Angle | 60 | |

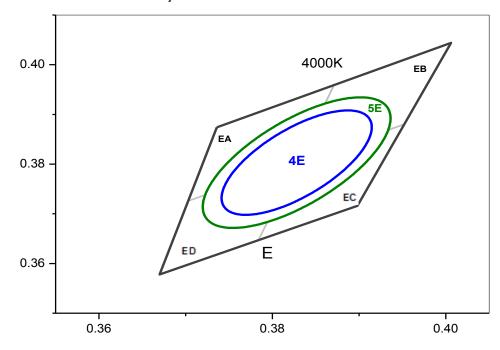
| 6500 | K 5Step | 5700 | K 5Step | 5000K 5Step | | |
|---------------------------|-----------------|---------------------------|-----------------|---------------------------|-----------------|--|
| | 5A | | 5B | 5C | | |
| Center point | 0.3123 : 0.3282 | Center point | 0.3287 : 0.3417 | Center point | 0.3447 : 0.3553 | |
| Major Axis a | 0.0110 | Major Axis a | 0.0118 | Major Axis a | 0.0135 | |
| Minor Axis b | 0.0045 | Minor Axis b | 0.0050 | Minor Axis b | 0.0058 | |
| Ellipse Rotation Angle | 58 | Ellipse Rotation Angle | 59 | Ellipse Rotation Angle | 60 | |

| A | Α | A | В | A | С | A | D |
|--------|--------|--------|--------|--------|--------|--------|--------|
| CIE X | CIE Y |
| 0.3028 | 0.3304 | 0.3115 | 0.3393 | 0.3131 | 0.329 | 0.3048 | 0.3209 |
| 0.3048 | 0.3209 | 0.3131 | 0.329 | 0.3146 | 0.3187 | 0.3068 | 0.3113 |
| 0.3131 | 0.329 | 0.3213 | 0.3371 | 0.3221 | 0.3261 | 0.3146 | 0.3187 |
| 0.3115 | 0.3393 | 0.3205 | 0.3481 | 0.3213 | 0.3371 | 0.3131 | 0.329 |
| В | A | В | В | В | C | В | D |
| CIE X | CIE Y |
| 0.3207 | 0.3462 | 0.3292 | 0.3539 | 0.3293 | 0.3423 | 0.3215 | 0.3353 |
| 0.3215 | 0.3353 | 0.3293 | 0.3423 | 0.3294 | 0.3306 | 0.3222 | 0.3243 |
| 0.3293 | 0.3423 | 0.3371 | 0.3493 | 0.3366 | 0.3369 | 0.3294 | 0.3306 |
| 0.3292 | 0.3539 | 0.3376 | 0.3616 | 0.3371 | 0.3493 | 0.3293 | 0.3423 |
| C | A | C | В | C | C | C | D |
| CIE X | CIE Y |
| 0.3376 | 0.3616 | 0.3463 | 0.3687 | 0.3452 | 0.3558 | 0.3371 | 0.3493 |
| 0.3371 | 0.3493 | 0.3452 | 0.3558 | 0.344 | 0.3428 | 0.3366 | 0.3369 |
| 0.3452 | 0.3558 | 0.3533 | 0.3624 | 0.3514 | 0.3487 | 0.344 | 0.3428 |
| 0.3463 | 0.3687 | 0.3551 | 0.376 | 0.3533 | 0.3624 | 0.3452 | 0.3558 |

Color Bin Structure

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CIE Chromaticity Diagram, T_j=85°C, I_F=700mA



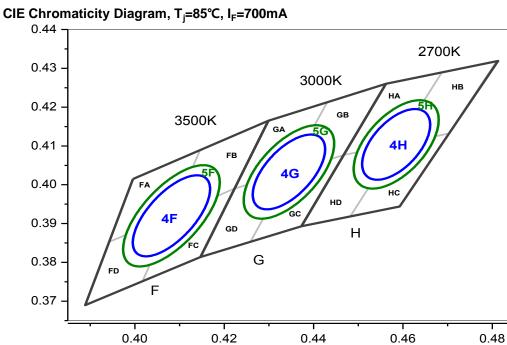
| 4000K 4Step | | | | |
|-----------------------|-----------------|--|--|--|
| 4E | | | | |
| Center point | 0.3818 : 0.3797 | | | |
| Major Axis a | 0.0125 | | | |
| Minor Axis b | 0.0053 | | | |
| Ellipse | 53 | | | |
| Rotation Angle | 53 | | | |

| 4000K 5Step | | | | |
|-----------------------|-----------------|--|--|--|
| 5E | | | | |
| Center point | 0.3818 : 0.3797 | | | |
| Major Axis a | 0.0157 | | | |
| Minor Axis b | 0.0067 | | | |
| Ellipse | 53 | | | |
| Rotation Angle | 53 | | | |

| E | A | E | В | E | c | E | D |
|--------|--------|--------|--------|--------|--------|--------|--------|
| CIE X | CIE Y |
| 0.3736 | 0.3874 | 0.3871 | 0.3959 | 0.3828 | 0.3803 | 0.3703 | 0.3726 |
| 0.3703 | 0.3726 | 0.3828 | 0.3803 | 0.3784 | 0.3647 | 0.367 | 0.3578 |
| 0.3828 | 0.3803 | 0.3952 | 0.388 | 0.3898 | 0.3716 | 0.3784 | 0.3647 |
| 0.3871 | 0.3959 | 0.4006 | 0.4044 | 0.3952 | 0.388 | 0.3828 | 0.3803 |

Color Bin Structure

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| 3500K 4Step | | 3000K 4Step | | 2700K 4Step | |
|---------------------------|-----------------|---------------------------|-----------------|---------------------------|-----------------|
| | 4F | 4G | | 4H | |
| Center point | 0.4073 : 0.3917 | Center point | 0.4338 : 0.4030 | Center point | 0.4578 : 0.4101 |
| Major Axis a | 0.0124 | Major Axis a | 0.0113 | Major Axis a | 0.0105 |
| Minor Axis b | 0.0055 | Minor Axis b | 0.0055 | Minor Axis b | 0.0055 |
| Ellipse Rotation Angle | 53 | Ellipse Rotation Angle | 53 | Ellipse Rotation Angle | 54 |

| 3500K 5Step | | 3000K 5Step | | 2700K 5Step | |
|----------------|-----------------|-----------------------|-----------------|----------------|-----------------|
| | 5F | 5G | | 5H | |
| Center point | 0.4073 : 0.3917 | Center point | 0.4338 : 0.4030 | Center point | 0.4578 : 0.4101 |
| Major Axis a | 0.0155 | Major Axis a | 0.0142 | Major Axis a | 0.0132 |
| Minor Axis b | 0.0068 | Minor Axis b | 0.0068 | Minor Axis b | 0.0068 |
| Ellipse | 53 | Ellipse | 53 | Ellipse | 54 |
| Rotation Angle | | Rotation Angle | | Rotation Angle | 54 |

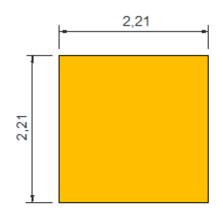
| F | A | F | В | F | С | F | D |
|--------|--------|--------|--------|--------|--------|--------|--------|
| CIE X | CIE Y |
| 0.3996 | 0.4015 | 0.4146 | 0.4089 | 0.4082 | 0.392 | 0.3943 | 0.3853 |
| 0.3943 | 0.3853 | 0.4082 | 0.392 | 0.4017 | 0.3751 | 0.3889 | 0.369 |
| 0.4082 | 0.392 | 0.4223 | 0.399 | 0.4147 | 0.3814 | 0.4017 | 0.3751 |
| 0.4146 | 0.4089 | 0.4299 | 0.4165 | 0.4223 | 0.399 | 0.4082 | 0.392 |
| G | A | G | В | G | с | G | D |
| CIE X | CIE Y |
| 0.4299 | 0.4165 | 0.443 | 0.4212 | 0.4345 | 0.4033 | 0.4223 | 0.399 |
| 0.4223 | 0.399 | 0.4345 | 0.4033 | 0.4259 | 0.3853 | 0.4147 | 0.3814 |
| 0.4345 | 0.4033 | 0.4468 | 0.4077 | 0.4373 | 0.3893 | 0.4259 | 0.3853 |
| 0.443 | 0.4212 | 0.4562 | 0.426 | 0.4468 | 0.4077 | 0.4345 | 0.4033 |
| н | A | н | В | н | C | н | D |
| CIE X | CIE Y |
| 0.4562 | 0.426 | 0.4687 | 0.4289 | 0.4585 | 0.4104 | 0.4468 | 0.4077 |
| 0.4468 | 0.4077 | 0.4585 | 0.4104 | 0.4483 | 0.3919 | 0.4373 | 0.3893 |
| 0.4585 | 0.4104 | 0.4703 | 0.4132 | 0.4593 | 0.3944 | 0.4483 | 0.3919 |
| 0.4687 | 0.4289 | 0.481 | 0.4319 | 0.4703 | 0.4132 | 0.4585 | 0.4104 |

S1W0-xxxxxxx03-00000000-x0001 - High-power LED

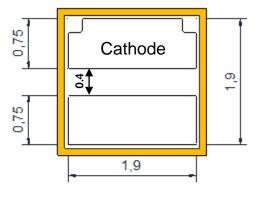
Mechanical Dimensions

S1W0-2222xxxx03-00000000-00001

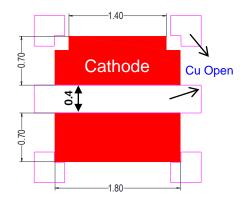
SEOUL



< Top >



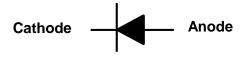
< Bottom >

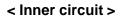






< Recommended Solder Pattern >





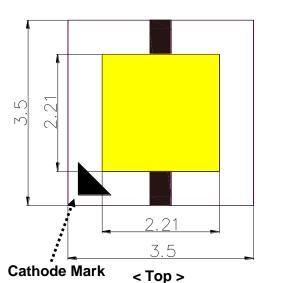
- (1) All dimensions are in millimeters.
- (2) Scale : none
- (3) Undefined tolerance is ± 0.13 mm

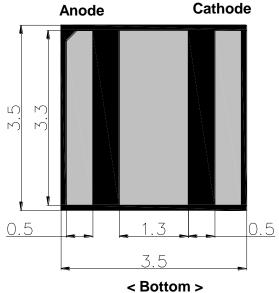
S1W0-xxxxxxx03-00000000-x0001 - High-power LED

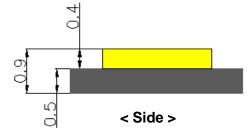
Mechanical Dimensions

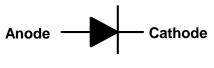
S1W0-2222xxxx03-00000000-P0001

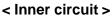
SEOUL











(1) All dimensions are in millimeters.

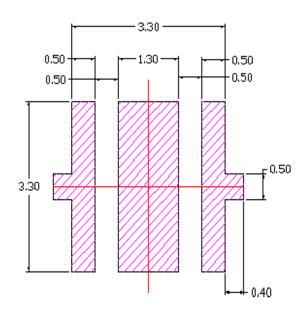
- (2) Scale : none
- (3) Undefined tolerance is ± 0.13 mm

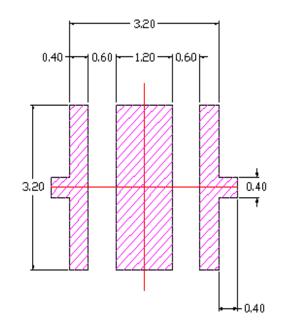
S1W0-xxxxxxx03-00000000-x0001 - High-power LED

Recommended Solder Pad

S1W0-2222xxxx03-00000000-P0001

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< Recommended PCB Solder Pad >

< Recommended Stencil Pattern >

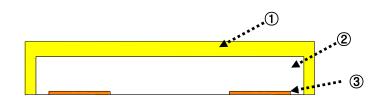
(1) All dimensions are in millimeters.

- (2) Scale : none
- (3) This drawing without tolerances are for reference only.
- (4) Undefined tolerance is ± 0.1 mm.

Material Structure

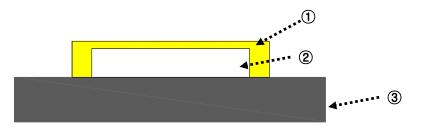
SEOUL

S1W0-2222xxxx03-0000000-00001



| No. | List Material | |
|-----|---------------|--------------------|
| 1 | Encapsulation | Silicone, Phosphor |
| 2 | Chip Source | GaN ON SAPPHIRE |
| 3 | Solder-PAD | Metal (Au) |

S1W0-2222xxxx03-00000000-P0001



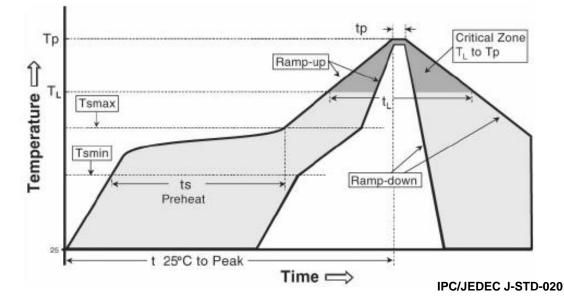
| No. | List | Material |
|-----|---------------|--------------------|
| 1 | Encapsulation | Silicone, Phosphor |
| 2 | Chip Source | GaN ON SAPPHIRE |
| 3 | Ceramic | AIN |



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S1W0-xxxxxxx03-00000000-x0001 - High-power LED

Reflow Soldering Characteristics



| Profile Feature | Pb-Free Assembly |
|---|------------------------------------|
| Average ramp-up rate (Tsmax to Tp) | 3° C/second max. |
| Preheat - Temperature Min (Tsmin) - Temperature Max (Tsmax) - Time (Tsmin to Tsmax) (ts) | 150 °C 180 °C 80-120 seconds |
| Time maintained above: - Temperature (TL) - Time (tL) | 217~220°C 80-100 seconds |
| Peak Temperature (Tp) | 250~255℃ |
| Time within 5°C of actual Peak Temperature (tp)2 | 20-40 seconds |
| Ramp-down Rate | 6 °C/second max. |
| Time 25°C to Peak Temperature | 8 minutes max. |
| Atmosphere | Nitrogen (O2<1000ppm) |

Caution

- (1) Reflow soldering is recommended not to be done more than two times. In the case of more than 24 hours passed soldering after first, LED will be damaged.
- (2) Re-soldering should not be done after the LED have been soldered. If re-soldering is
- unavoidable, LED's characteristics should be carefully checked before and after such repair.. (3) Do not put stress on the LED during heating.
- (4) After reflow, do not clean PCB by water or solvent.

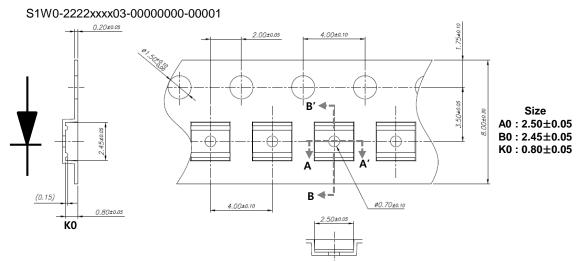
SMT recommendation

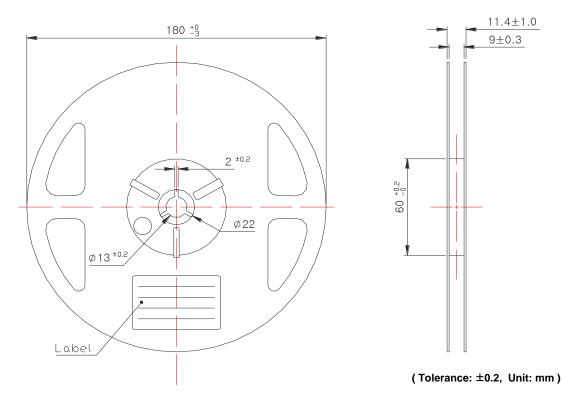
- (1) After reflow, Over 80% reflectance of PSR is recommended. → Tamura RPW-8000-xx
- (2) Solder paste materials (SAC 305, No Cleaning Paste) → Senju M705-GRN360-K2-V
- (3) We recommend Turn On Voltage(TOV) Test 1.8v~2.8v at 1uA (per LED)
- (4) We recommend IR Test 0~1uA at -5V (per LED)

SEOUL

S1W0-xxxxxxx03-00000000-x0001 - High-power LED

Emitter Tape & Reel Packaging





Notes :

(1) Quantity : 1,000pcs/Reel

(empty slot possible in taping reel)

(2) Cumulative Tolerance : Cumulative Tolerance/10 pitches to be $\pm 0.2 \text{mm}$

(3) Adhesion Strength of Cover Tape : Adhesion strength to be 0.1-0.7N when the cover

tape is turned off from the carrier tape at the angle of 10° to the carrier tape

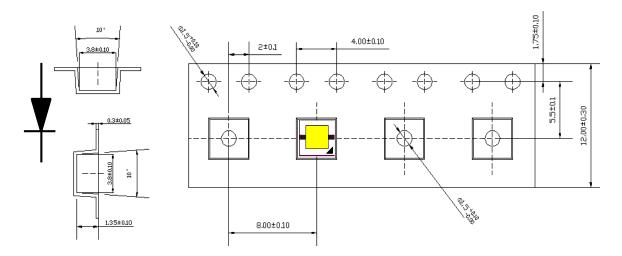
(4) Package : P/N, Manufacturing data Code No. and quantity to be indicated on a damp proof Package

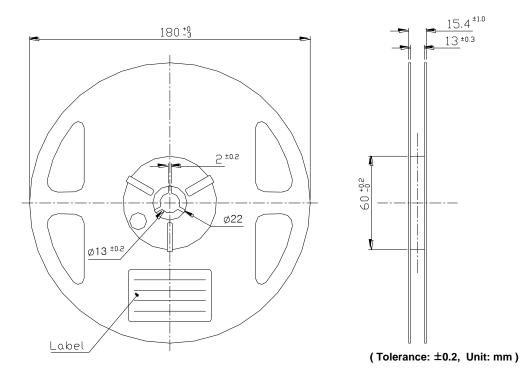
S1W0-xxxxxxx03-00000000-x0001 - High-power LED

Emitter Tape & Reel Packaging

S1W0-2222xxxx03-00000000-P0001

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Notes :

(1) Quantity : 1,000pcs/Reel

(empty slot possible in taping reel)

(2) Cumulative Tolerance : Cumulative Tolerance/10 pitches to be \pm 0.2mm

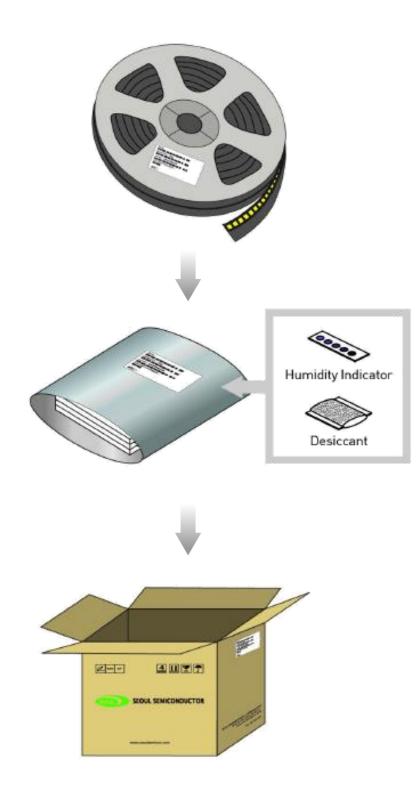
(3) Adhesion Strength of Cover Tape : Adhesion strength to be 0.1-0.7N when the cover

tape is turned off from the carrier tape at the angle of 10° to the carrier tape

(4) Package : P/N, Manufacturing data Code No. and quantity to be indicated on a damp proof Package



Packaging Information



SEOUL

S1W0-xxxxxxx03-00000000-x0001 - High-power LED

Product Nomenclature

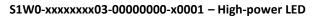
Table 6. Part Numbering System : $X_1X_2X_3X_4X_5X_6X_7X_8-X_9$

| Part Number Code | Description | Part Number | Value |
|---|-----------------------------------|-------------|---------------------|
| X ₁ | Company | S | Seoul Semiconductor |
| X ₂ | Level of Integration | 1 | Discrete LED |
| X ₃ X ₄ | Technology | W0 | General White |
| | | | |
| X ₅ X ₆ X ₇ X ₈ | Dimension | 2222 | |
| X ₉ X ₁₀ | CCT | 40 | |
| X ₁₁ X ₁₂ | CRI | 70 | |
| X ₁₃ X ₁₄ | Vf | 03 | |
| | | | |
| X ₁₅ X ₁₆ X ₁₇ | Characteristic code Flux Rank | 000 | |
| X ₁₈ X ₁₉ X ₂₀ | Characteristic code Vf Rank | 000 | |
| X ₂₁ X ₂₂ | Characteristic code Color Step | 00 | |
| | | | |
| X ₂₃ X ₂₄ | Туре | 00 (P0) | |
| X ₂₅ X ₂₆ X ₂₇ | Internal code | 001 | |

Notes :

(1) Tolerance is $\pm 0.06V$ on forward voltage measurements.

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Handling of Silicone Resin for LED

(1) During processing, mechanical stress on the surface should be minimized as much as possible. Sharp objects of all types should not be used to pierce the sealing compound.



- (2) Do not use tweezers to pick up or handle WICOP LED. A vacuum pick up should only be used.
- (3) When populating boards in SMT production, there are basically no restrictions regarding the form of the pick and place nozzle, except that mechanical pressure on the surface of the resin must be prevented. This is assured by choosing a pick and place nozzle which is smaller than the LED's area.
- (4) Silicone differs from materials conventionally used for the manufacturing of LED. These conditions must be considered during the handling of such devices. Compared to standard encapsulants, silicone is generally softer, and the surface is more likely to attract dust. As mentioned previously, the increased sensitivity to dust requires special care during processing.
- (5) Please do not mold this product into another resin (epoxy, urethane, etc) and do not handle this product with acid or sulfur material in sealed space.
- (6) Avoid leaving fingerprints on silicone resin parts.



Precaution for Use

(1) Storage

To avoid the moisture penetration, we recommend storing LED in a dry box with a desiccant . The recommended storage temperature range is 5° C to 30° C and a maximum humidity of RH50%.

(2) Use Precaution after Opening the Packaging

Use proper SMD techniques when the LED is to be soldered dipped as separation of the lens may affect the light output efficiency.

Pay attention to the following:

- a. Recommend conditions after opening the package
 - Sealing / Temperature : 5 ~ 30°C Humidity : less than RH60%
- b. If the package has been opened more than 1 year (MSL 2) or the color of

the desiccant changes, components should be dried for 10-24hr at $65\pm5^\circ\!C$

(3) Do not apply mechanical force or excess vibration during the cooling process to normal temperature after soldering.

(4) Do not rapidly cool device after soldering.

(5) Components should not be mounted on warped (non coplanar) portion of PCB.

(6) Radioactive exposure is not considered for the products listed here in.

(7) Gallium arsenide is used in some of the products listed in this publication. These products are dangerous if they are burned or shredded in the process of disposal. It is also dangerous to drink the liquid or inhale the gas generated by such products when chemically disposed of.

(8) This device should not be used in any type of fluid such as water, oil, organic solvent and etc.

(9) When the LED are in operation the maximum current should be decided after measuring the package temperature.

(10) The appearance and specifications of the product may be modified for improvement without notice.

(11) Long time exposure of sunlight or occasional UV exposure will cause lens discoloration.



Precaution for Use

(12) VOCs (Volatile organic compounds) emitted from materials used in the construction of fixtures ca n penetrate silicone encapsulants of LED and discolor when exposed to heat and photonic energy. Th e result can be a significant loss of light output from the fixture. Knowledge of the properties of the mat erials selected to be used in the construction of fixtures can help prevent these issues.

(13) Attaching LED, do not use adhesives that outgas organic vapor.

(14) The driving circuit must be designed to allow forward voltage only when it is ON or OFF. If the rev erse voltage is applied to LED, migration can be generated resulting in LED damage.

(15) LED is sensitive to Electro-Static Discharge (ESD) and Electrical Over Stress (EOS). Below is a li st of suggestions that Seoul Semiconductor purposes to minimize these effects.

a. ESD (Electro Static Discharge)

Electrostatic discharge (ESD) is the defined as the release of static electricity when two objects come into contact. While most ESD events are considered harmless, it can be an expensive problem in many industrial environments during production and storage. The damage from ESD to an LEDs may cause the product to demonstrate unusual characteristics such as:

- Increase in reverse leakage current lowered turn-on voltage
- Abnormal emissions from the LED at low current

The following recommendations are suggested to help minimize the potential for an ESD event. One or more recommended work area suggestions:

- Ionizing fan setup
- ESD table/shelf mat made of conductive materials
- ESD safe storage containers

One or more personnel suggestion options:

- Antistatic wrist-strap
- Antistatic material shoes
- Antistatic clothes

Environmental controls:

- Humidity control (ESD gets worse in a dry environment)



Precaution for Use

b. EOS (Electrical Over Stress)

Electrical Over-Stress (EOS) is defined as damage that may occur when an electronic device is subjected to a current or voltage that is beyond the maximum specification limits of the device. The effects from an EOS event can be noticed through product performance like:

- Changes to the performance of the LED package

(If the damage is around the bond pad area and since the package is completely encapsulated the package may turn on but flicker show severe performance degradation.)

- Changes to the light output of the luminaire from component failure
- Components on the board not operating at determined drive power

Failure of performance from entire fixture due to changes in circuit voltage and current across total circuit causing trickle down failures. It is impossible to predict the failure mode of every LED exposed to electrical overstress as the failure modes have been investigated to vary, but there are some common signs that will indicate an EOS event has occurred:

- This damage usually appears due to the thermal stress produced during the EOS event.

c. To help minimize the damage from an EOS event Seoul Semiconductor recommends utilizing:

- A surge protection circuit
- An appropriately rated over voltage protection device
- A current limiting device





Company Information

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Company Information

Seoul Semiconductor (www.SeoulSemicon.com) manufacturers and packages a wide selection of light emitting diodes (LED) for the automotive, general illumination/lighting, Home appliance, signage and back lighting markets. The company is the world's fifth largest LED supplier, holding more than 10,000 patents globally, while offering a wide range of LED technology and production capacity in areas such as "nPola", "Acrich", the world's first commercially produced AC LED, and "Acrich MJT - Multi-Junction Technology" a proprietary family of high-voltage LED.

The company's broad product portfolio includes a wide array of package and device choices such as Acrich and Acirch2, high-brightness LED, mid-power LED, side-view LED, and through-hole type LED as well as custom modules, displays, and sensors.

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